

Journal of Applied Sciences

ISSN 1812-5654





An Accurate Model of 555IC Astable Multivibrator

Shahid Iqbal, Ghanshyam Kumar Singh and Rosli Besar

Faculty of Engineering and Technology, Multimedia University, Melaka Campus, 75450 Melaka, Malaysia

Abstract: An accurate model of 555IC astable multivibrator circuit has been presented in this paper. The closure resistance of the discharge transistor, which was ignored in the previous analysis, has been taken into consideration in this model. The equations developed in the model are plotted in Matlab. The plot of these equations shows that when $R_A << R_B$ the discharging time becomes much larger than the charging time and the duty cycle of the output waveform becomes much smaller than 50%. These results has been found in complete agreement with experimental results for all values of R_A and R_B .

Key words: 555IC, astable multivibrator, closure resistance

INTRODUCTION

Although 555IC was introduced 30 years ago, still today is the most used IC. It has many applications such as pulse generation, precision timing, sequential timing, time delay generation, pulse width modulation, pulse position modulation and linear ramp generation^[1,2]. One of its application pulse generation in which the 555IC operates as a table multivibrator is widely used in undergraduate laboratories. In the astable multivibrator mode the timer is connected to two external resistors R_b and R_B and one capacitor C as shown in Fig. 1. The duty cycle of the output waveform is controlled by the charging and discharging of the RC network^[1,2]. This circuit is analysed and discussed in the data sheets of 555 IC[1,2] and almost in every electronics book which contains a chapter on oscillators [1-5]. In all these references the calculation of duty cycle is described as that when the output of the timer is high the capacitor C charges through R_A and R_B to a value $(2/3)V_{cc}$ (Fig. 2). When the output of the timer is low the capacitor C discharges through R_B and discharge transistor Q_1 to a value $(1/3)V_{CC}$. The charging time of the capacitor is given as^[1-5].

$$T_{c} = 0.693(R_{A} + R_{B})C$$
 (1)

This discharging time of the capacitor is given as^[1-5].

$$T_{p} = 0.693 R_{p} C$$
 (2)

The frequency of oscillation f and the duty cycle D is given as^[1-4]:

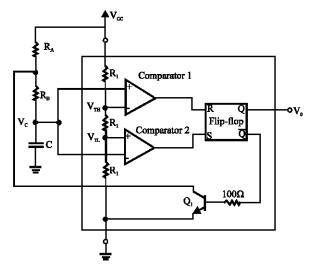


Fig. 1: 555 IC astable multivibrator circuit

$$f = \frac{1}{T} = \frac{1}{T_c + T_p} = \frac{1}{0.693(R_A + R_B)C}$$
 (3)

and

$$D = \frac{T_{c}}{T} \times 100\% = \frac{R_{A} + R_{B}}{R_{A} + 2R_{B}} \times 100\%$$
 (4)

The Eq. 4 shows that the duty cycle for this circuit is always greater than 50%. The duty cycle approaches 50% for $R_A{<<}R_B^{\ [1.5]}$. However in this research it has been found experimentally that duty cycle is less than 50% for $R_A{<<}R_B$. This is in contradiction with the Eq. 4. Therefore expression (4) and hence (2 and 3) are not valid for $R_A{<<}R_B$. To answer for the experimental results, a new model is derived, taking into account the closure resistance of the discharge transistor.

Corresponding Author: Shahid Iqbal, Faculty of Engineering and Technology, Multimedia University,

Melaka Campus, 75450 Melaka, Malaysia

Tel: 0060 12 6627116 Fax: 0060 6 2316552 E-mail: Shahid.iqbal@mmu.edu.my

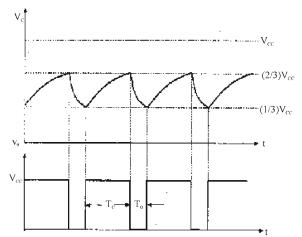


Fig. 2: Typical operating waveform of 555 IC astable multivibrator

DERIVATION OF THE MODEL

The two comparators along with RS flip-flop function as a switch at the base of the discharge transistor Q_1 . Therefore the circuit of the Fig. 1 can be redrawn to the one shown in Fig. 3 which is more convenient for the calculation of the charging and discharging times.

When the switch 'S' is open the transistor Q_1 is in off state and the capacitor will charge through R_A and R_B . The charging time T_C is same as given by Eq. 1. When the switch 'S' is closed the transistor Q_1 will be in saturation state and it will behave as a closed switch with a small closure resistance $R_{\text{CE(Sat)}}$. Therefore the transistor can be replaced by a closure resistance $R_{\text{CE(Sat)}}$ as shown in Fig. 4. The closure resistance $R_{\text{CE(Sat)}}$ of the discharge transistor is the slope of the I_C verses V_{CE} and is given as I_C

$$R_{CE(Sat)} = \frac{\Delta VCE_{(sat)}}{\Delta I_C}$$
 (5)

where, $I_C = I_1 + I_2$

From the $I_{\text{C}}\text{-}V_{\text{CE}}$ characteristics of the discharge transistor the closure resistance was found to be approximately 10 Ω from 1 to 90 mA and beyond 90 mA the closure resistance starts increasing and when it becomes equal to $R_{\text{A}}/2$ the oscillator stops oscillating. The discharging time of the capacitor is calculated by considering the circuit shown in Fig. 4. The complete response of the circuit shown in Fig. 4 is sum of natural response and forced response. The natural response can be evaluated by setting $V_{\text{CC}}=0$ and finding the Thevenin resistance faced by the capacitor

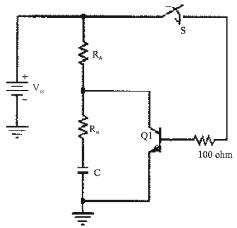


Fig. 3: Equivalent switching circuit

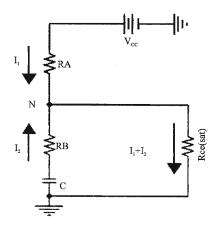


Fig. 4: Equivalent circuit when output of timer is low

$$R_{eq} = R_{B} + \frac{R_{\Lambda} R_{CE(Sat)}}{R_{\Lambda} + R_{CE(Sat)}}$$
 (6)

and

$$V_{c_n} = A \exp(\frac{-t}{R C}) \tag{7}$$

Now to evaluate the forced response the capacitor is treated to be open circuit and the forced voltage V_{Cf} are given as:

$$V_{\rm Cf} = \frac{R_{\rm CE(Sat)} V_{\rm CC}}{R_{\rm A} + R_{\rm CE(Sat)}}$$
(8)

The complete response is:

$$V_{\rm c} = \frac{R_{\rm CE(Sat)} V_{\rm CC}}{R_{\Lambda} + R_{\rm CE(Sat)}} + A \exp(\frac{-t}{RC})$$
 (9)

Applying initial condition $V_c = \frac{2}{3}V_{cc}$ at t = 0

$$A = \frac{2}{3} V_{cc} - \frac{R_{ce(Sat)}}{R_A + R_{ce(sat)}} V_{cc}$$
 (10)

Using Eq. 16 into 15:

$$V_{_{\mathrm{C}}} = \frac{R_{_{^{\mathrm{CE(Sat)}}}}V_{_{\mathrm{CC}}}}{R_{_{\mathrm{A}}} + R_{_{^{\mathrm{CE(Sat)}}}}} + \left(\frac{2}{3}\,V_{_{\mathrm{CC}}} - \frac{R_{_{^{\mathrm{CE(Sat)}}}}}{R_{_{\mathrm{A}}} + R_{_{^{\mathrm{CE(Sat)}}}}}\,V_{_{\mathrm{CC}}}\right) exp(\frac{-t}{RC})$$

Applying final condition $V_c = \frac{1}{3} V_{cc}$ at $t = T_D$

$$\frac{1}{3}V_{\text{CC}} = \frac{R_{\text{CE(Sat)}}V_{\text{CC}}}{R_{\text{A}} + R_{\text{CE(Sat)}}} + \left(\frac{2}{3}V_{\text{CC}} - \frac{R_{\text{CE(Sat)}}}{R_{\text{A}} + R_{\text{CE(Sat)}}}V_{\text{CC}}\right) exp(\frac{-T_{\text{D}}}{RC})$$

ОΓ

$$\frac{R_{A} - 2R_{\text{CE(Sat)}}}{2R_{A} - R_{\text{CE(Sat)}}} = exp(\frac{-T_{\text{D}}}{RC})$$
 (11)

Solving Eq. 17 for T_D :

$$T_{D} = RCln\left(\frac{R_{CE(Sat)} - 2R_{A}}{2R_{CE(Sat)} - R_{A}}\right)$$
(12)

Use of Eq. 12 into 18, yields:

$$T_{D} = \left(R_{B} + \frac{R_{A}R_{CE(Sat)}}{R_{A} + R_{CE(Sat)}}\right)Cln\left(\frac{R_{CE(Sat)} - 2R_{A}}{2R_{CE(Sat)} - R_{A}}\right)$$
(13)

Figure 5 shows the plot of Eq. 13 in MATLAB. The Fig. 5 shows that the discharging time of capacitor is increases exponentially with decrease in the resistance $R_{\rm A}.$ Equation 13 is valid only for, $R_{\text{CE(Sat)}} {\leq} R_{\text{A}}/2$. This is due to the reason that when $R_{\text{CE(Sat)}} {\leq} R_{\text{A}}/2$ then Eq. 13 becomes negative which is not possible and also at $R_{\text{CE(Sat)}} {\leq} R_{\text{A}}/2$ the forced voltage across the capacitor becomes larger than $1/3V_{\text{CC}}$ and oscillation stops. The duty cycle of the waveform is given as:

$$D = \frac{0.693(R_A + R_B)}{0.693(R_A + R_B) + \left[\left(R_B + \frac{R_A R_{CE(Sat)}}{R_A + R_{CE(Sat)}} \right) \ln \left(\frac{R_{CE(Sat)} - 2R_A}{2R_{CE(Sat)} - R_A} \right) \right]}$$
(14)

Figure 6 and 7 shows the plot of Eq. 14 in MATLAB. The Fig. 6 illustrate that the duty cycle of the wave form

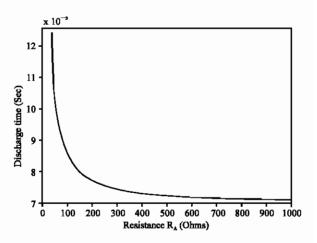


Fig. 5: Plot of Eq. 13 (C = 0.1 uF, $R_{\text{CE(Sat)}}$ = 10 Ω , R_{B} = 100 k Ω and R_{A} = 40~1000 Ω)

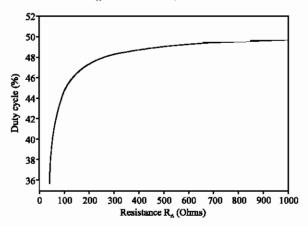


Fig. 6: Plot of Eq. 14 (R_{CE(Sa)} = 10 Ω , R_B = 100 k Ω and R_A= 40 Ω – 1000 Ω)

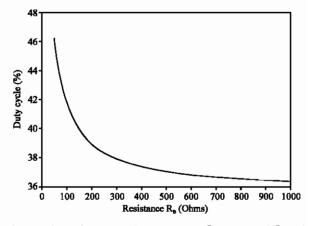


Fig. 7: Plot of Eq. 14 ($R_{\text{CE(Sat)}}$ = 10 Ω , R_{A} = 40 k Ω and R_{B} = 50 Ω \rightarrow 1000 Ω)

decreases exponentially with the decrease in the resistance $R_{\mbox{\tiny A}}.$

RESULTS AND DISCUSSION

In experiment the parameter of the Astable multivibrator circuit shown in Fig. 1 was set to as: $V_{CC} = 5V$, $R_B = 100 \text{ k}\Omega$, C = 0.1 uF and R_A was varied from

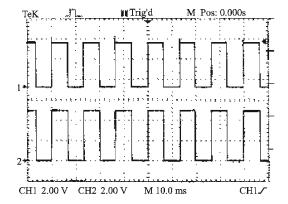


Fig. 8: Output Waveform (upper) and waveform at the pin 7 (lower); RA = 1 k Ω , R_B = 100 k Ω , R_{CE(Sat)} = 10 Ω and C = 0.1 uF

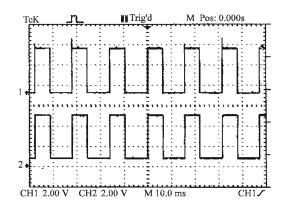


Fig. 9: Output Waveform (upper) and waveform at the pin 7 (lower); RA = 47 k Ω , R_{B} = 100 k Ω , $R_{CE(Sat)}$ = 10 Ω and C = 0.1 uF

10 k Ω to 33 Ω . The experimental results are presented in Fig. 8-10, which shows the waveform at the output of the timer (upper) and at the pin 7 (lower), for $R_A=1$ k Ω , $R_A=47$ Ω and for $R_A=33$ Ω , respectively. The results shows that the duty cycle is slightly less than 50% and this is in agreement with the theoretically results presented in Fig. 6. The experimental results shown in Fig. 8-10 are completely in agreement with theoretical results presented in Fig. 6 and 7. It was found that as long as $R_A \ge 40$ Ω , the closure resistance $R_{CE(Sal)}$ is 10 Ω . At $R_A=33$ Ω the closure resistance is increase to 15 Ω and therefore using this value in expression (14), the corresponding duty cycle can be obtained.

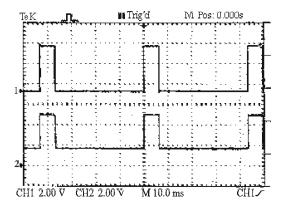


Fig. 10: Output Waveform (upper) and waveform at the pin 7 (lower); RA = 33 k Ω , R_B = 100 k Ω , $R_{CE(Sat)}$ = 15 Ω and C = 0.1 uF

CONCLUSIONS

In this paper it has been presented successfully that the previous model of 555 IC astable multivibrator circuit of Fig. 1 is invalid for $R_A \!\!<\!\! <\!\! R_B$. This failure is due to ignorance of the closure resistance of the discharge transistor in that model. Hence taking in account the closure resistance of discharge transistor a new model has been developed. This presented model is valid for all values of R_A and R_B and is completely in agreement with experimental results.

REFERENCES

- Data Sheets of LM555. National Semiconductors Inc. http://www.national.com/pf/LM/LM555.html#Datas heet
- Data Sheets of NE555. Fairchild semiconductor Inc. http://www.fairchildsemi.com/ds/NE/NE555.pdf
- Donald, A.N., 2001. Electronic Circuit Analysis and Design. 2nd Edn., Mc Graw Hill,
- Sedra and Smith, 2003. Microelectronic Circuits. 2nd Edn., Oxford Uiversity Press,
- 5. Robert, L.B. and N. Louis, 2002. Electronic Devices and Circuit Theory. 8th Edn., Prentice Hall.